B.E. Electronics & Telecommunication / Communication Engineering Seven Semester (CBS) EC703 - Opto Electronics Devices and Communication

	Pages : ne : Th	2 aree Hours $\star 1 4 0 4 \star$	GUG/W/18/1794 Max. Marks : 80
	Note	 es: 1. All questions carry equal marks. 2. Assume suitable data wherever necessary. 3. Illustrate your answers wherever necessary with the help of near 	t sketches.
1.	a)	Draw the block diagram of optical communication system. Give the adv communication as compared with microwave links. Mention disadvanta	0 1
	b)	Consider a fiber with 25 μ m core radius. Core index n ₁ = 1.48 and $\Delta = 0$ i) If $\lambda = 1320$ nm, what is the value of V and how many modes propagii) What percent of optical power flows in the claddings ?	
		OR	
2.	a)	Explain the terms :ii)Hybrid modesii)LP Modesii)Hybrid modesiii)Degenerate modesiv)Leaky modes	8
	b)	Prove that for step index fiber a mode remains guided when $n_2k < \beta < n_1k$ where, symbols have their usual meaning.	8
3.	a)	What are the different types of attenuation losses in optical fiber ? Expla	in in brief. 8
	b)	What is pulse broadening in optical fiber ? Explain how it is related with Derive necessary relationship.	a group delay ? 8
		OR	
4.	a)	A certain optical fiber has attenuation of 1.4 dB/km at 1200 nm. If 0.5 m power is initially launched into the fiber, what is the power level in micr 7 km and 15 km ?	1
	b)	Define a connector. What are basic requirements of connector ? Discuss connectors.	different types of 8
5.	a)	Discuss absorption, spontaneous emission and stimulated emission proce detail.	ess of LASERs in 8
	b)	A lens coupled surface emitting LED launches 600 microwatt of optical index fiber. Determine the overall power conversion efficiency if it is op drive current of 100 mA and forward voltage of 1.9 V. If numerical aper estimate the coupling efficiency and optical losses in dB.	berating with a

OR

6.	a)	Draw the schematic of edge-emitting LED and explain its working.	
	b)	What are direct band gap materials ? Explain why direct band gap materials are suitable for manufacturing of optical sources.	8
7.	a) Discuss the basic requirement of photo detector. Define quantum efficiency and responsivity of photo detectors and obtain the relation between them.		8
	b)	A given Si avalanche photodiode has a quantum efficiency of 65% at a wavelength of 900 nm. Suppose 0.6 μ w of optical power produces a multiplied photo current of 10A. Find the multiplication factor M.	8
		OR	
8.	a)	Draw the schematic diagram of optical receiver and explain its working. Explain the various noise sources in the optical receiver.	8
	b)	Explain the working principle of an avalanche photodiode. Draw its equivalent circuit.	8
9.	a)	Describe with the aid of block diagram the working of WDM system.	8
	b)	Explain backscatter method of fiber attenuation measurement. Compare this method with cutback method of attenuation measurement.	8

OR

10. Write short notes on :

- SONET i)
- Eye pattern technique ii)
- iii) RZ, NRZ codes
- iv) LAN configuration using fiber optics.

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